

TDA7212

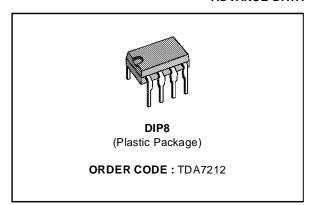
LOW VOLTAGE FM XTAL CONTROLLED FRONT-END

ADVANCE DATA

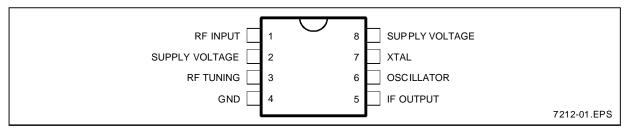
- RF PREAMPLIFIER
- BALANCED MIXER
- XTAL CONTROLLED OSCILLATOR (fundamental and overtone)
- LOW OSCILLATOR RADIATION
- HIGH SIGNAL HANDLING

DESCRIPTION

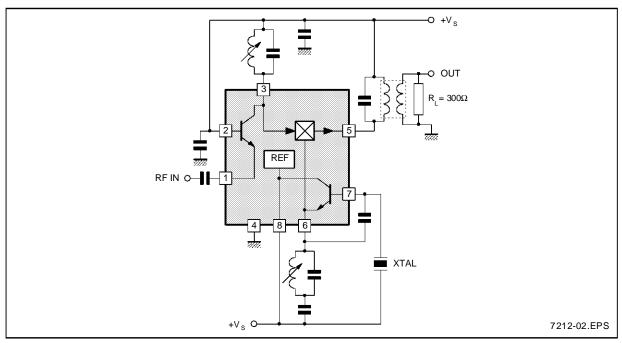
The TDA7212 is a monolithic integrated circuit in a 8 pin minidip package designed for general purpose XTAL controlled FM front-end up to 140MHz.



PIN CONNECTIONS



BLOCK DIAGRAM



August 1992 1/4

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit]
Vs	Supply Voltage	7	V	
P _{tot}	Total Power Dissipation at T _{amb} < 70°C	400	mW	ם
Toper	Operating Temperature	-20 , +85	°C	2
T_{stg}, T_{j}	Storage and Junction Temperature	-40, +150	°C	7212

THERMAL DATA

THERMAL DATA							
Symbol	Parameter		Value	Unit	2-02.		
R _{th (j-a)}	Junction-ambient Thermal Resistance	Max.	200	°C/W	721		

ELECTRICAL CHARACTERISTICS

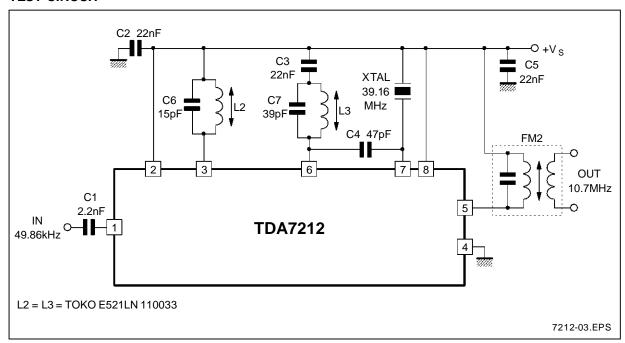
(Vs = 3V, T_{amb} = 25°C unless otherwise specified - Refer to the Test Circuit)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vs	Supply Voltage			3	6	V
Is	Supply Current			3		mA
Vosc	Local Oscillator Voltage (Pin 6)			200		mV _{RMS}
G	Voltage Gain	$f=49MHz,R_{IN}=75\Omega,R_{OUT}=300\Omega$		40		dB
V _{off}	Local Oscillator Stop Voltage			1.2		V

TYPICAL DC VOLTAGES (Refer to the Test Circuit)

Pins	1	2	3	4	5	6	7	8
(V)	2.3	3	3	0	3	2.1	2.9	3

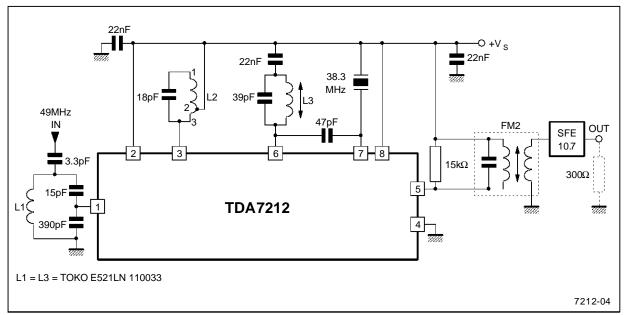
TEST CIRCUIT



7212-04.TBL

7212-03.TBL

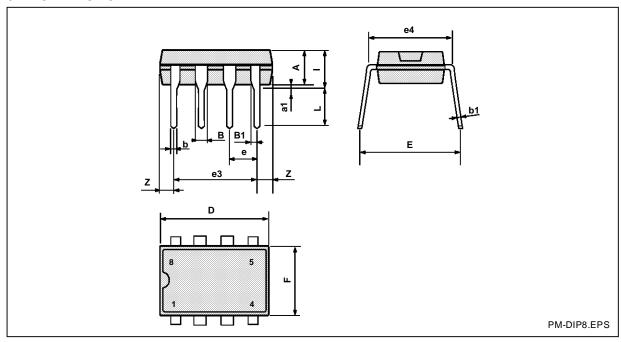
FRONT-END CORDLESS APPLICATION



NB.: In this application it is advisable to decrease the gain of the front-end through a tapping on the L2 coil (3 turns of 12). So it can be obtained: better selectivity, improved intermodulation performance, better matching with the following block that are IC's designed for double conversion radio receivers.

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches			
Dimensions	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
Е	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0260	
i			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	

DIP8.TBL

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